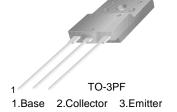


TIP140F/141F/142F

Monolithic Construction With Built In Base-Emitter Shunt Resistors

- Complement to TIP145F/146F/147F
- High DC Current Gain : $h_{FE} = 1000 @ V_{CE} = 4V, I_{C} = 5A (Min.)$
- Industrial Use

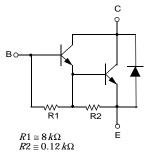


NPN Epitaxial Darlington Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage : TIP140F	60	V
	: TIP141F	80	V
	: TIP142F	100	V
	Collector-Emitter Voltage : TIP140F	60	V
V_{CEO}	: TIP141F	80	V
	: TIP142F	100	V
V_{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current (DC)	10	Α
I _{CP}	Collector Current (Pulse)	15	Α
I _B	Base Current (DC)	0.5	Α
P _C	Collector Dissipation (T _C =25°C)	60	W
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 65 ~ 150	°C

Equivalent Circuit



$\textbf{Electrical Characteristics} \ \, \textbf{T}_{\text{C}} = 25 \, ^{\circ} \text{C unless otherwise noted}$

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V _{CEO} (sus)	Collector-Emitter Sustaining Voltage : TIP140F : TIP141F : TIP142F	I _C = 30mA, I _B = 0	60 80 100			V V V
I _{CEO}	Collector Cut-off Current : TIP140F : TIP141F : TIP142F	$V_{CE} = 30V, I_{B} = 0$ $V_{CE} = 40V, I_{B} = 0$ $V_{CE} = 50V, I_{B} = 0$			2 2 2	mA mA mA
I _{CBO}	Collector Cut-off Current : TIP140F : TIP141F : TIP142F	$V_{CB} = 60V, I_{E} = 0$ $V_{CB} = 80V, I_{E} = 0$ $V_{CB} = 100V, I_{E} = 0$			1 1 1	mA mA mA
I _{EBO}	Emitter Cut-off Current	$V_{BE} = 5V, I_{C} = 0$			2	mA
h _{FE}	DC Current Gain	$V_{CE} = 4V, I_{C} = 5A$ $V_{CE} = 4V, I_{C} = 10A$	1000 500			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 5A, I_B = 10mA$ $I_C = 10A, I_B = 40mA$			2 3	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	$I_C = 10A, I_B = 40mA$			3.5	V
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = 4V, I_{C} = 10A$			3	V
t _D	Delay Time	$V_{CC} = 30V, I_{C} = 5A$		0.15		μs
t _R	Rise Time	$I_{B 1} = 20 \text{mA}, I_{B2} = -20 \text{mA}$		0.55		μs
t _{STG}	Storage Time	$R_L = 6\Omega$		2.5		μs
t _F	Fall Time			2.5	_	μs

Typical Characteristics

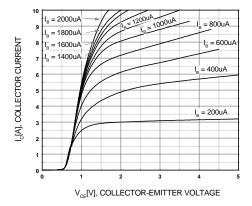


Figure 1. Static Characteristics

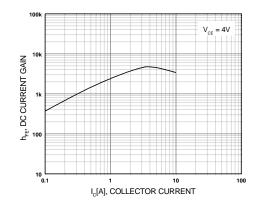


Figure 2. DC current Gain

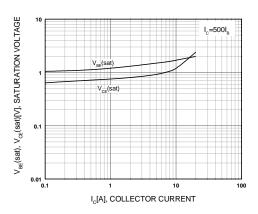


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

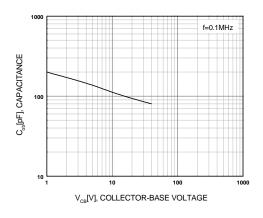


Figure 4. Collector Output Capacitance

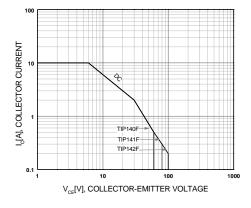


Figure 5. Safe Operating Area

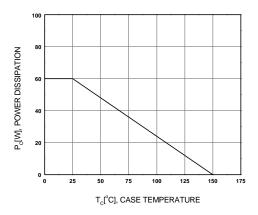
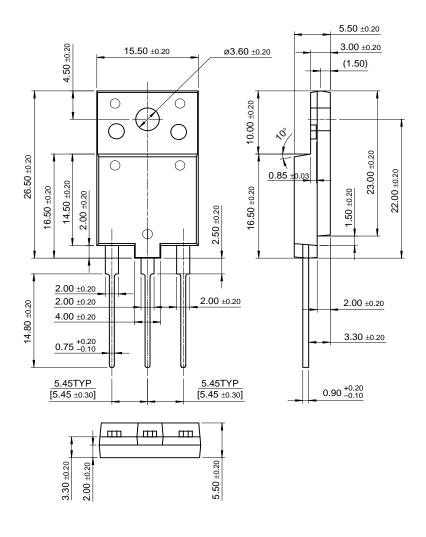


Figure 6. Power Derating

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Package Dimensions

TO-3PF



Dimensions in Millimeters

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E ² CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I ² C TM	OCX^{TM}	RapidConfigure™	UHC™
Across the board.	. Around the world.™	OCXPro™	RapidConnect™	UltraFET [®]
The Power Franchise™		OPTOLOGIC [®]	SILENT SWITCHER®	VCX™
Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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